

	<h2 style="color: red;">FQB10N50CFTM_WS</h2>
	<p><b>Hersteller-Teilenummer:</b> FQB10N50CFTM_WS</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> FQB10N50CFTM_WS Fairchild/ON Semiconductor</p> <p><b>Datenblätter:</b>  <a href="#">FQB10N50CFTM_WS.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB10N50CFTM_WS
Hersteller	Fairchild/ON Semiconductor
Beschreibung	FQB10N50CFTM_WS Fairchild/ON Semiconductor
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
Serie	FRFET®, QFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	143W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Tc)
Rds On (Max) @ Id, Vgs	610 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2210pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Original-Reel®















































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Sie können auch interessiert sein:

 <p><b>FQB10N60CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 9.5A D2PAK</p>	 <p><b>FQB10N60C</b> FSC FQB10N60C FSC</p>	 <p><b>FQB11N40</b> FSC FQB11N40 FSC</p>	 <p><b>FQB11N40C</b> FAIRCHI FQB11N40C FAIRCHI</p>
 <p><b>FQB10N20TM</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p>	 <p><b>FQB10N50CFTM-WS</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 10A DPAK</p>	 <p><b>FQB10N50CF</b> FAIRCHI FQB10N50CF FAIRCHI</p>	 <p><b>FQB10N50CFTM</b> FSC FQB10N50CFTM FSC</p>

### heiße Teile

Mehr

 FQB10N20C	 FQB10N20CTM	 FQB10N20CTM	 FQB10N20L	 FQB10N20LTM
 FQB10N20LTM	 FQB10N20TM	 FQB10N20TM	 FQB10N50CF	 FQB10N50CFTM
 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM	 FQB11N40	 FQB11N40C
 FQB11N40CTM	 FQB11N40CTM	 FQB11N60FTM	 FQB11N60TM	 FQB11P06
 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM	 FQB12N50TM_AM002
 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM	 FQB12N60CTM
 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10	 FQB12P10TM
 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM	 FQB13N06L
 FQB13N10	 FQB13N10L	 FQB13N50	 FQB13N50CTM	 FQB13N50CTM
 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM

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